35A Digital MicroDLynxII[™]: Non-Isolated DC-DC Power Modules

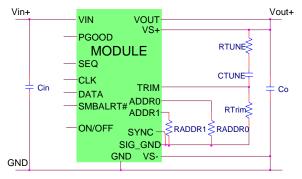
4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current



RoHS Compliant

Applications

- Distributed power architectures
- Intermediate bus voltage applications
- Telecommunications equipment
- Servers and storage applications
- Networking equipment
- Industrial equipment



Features

- Compliant to RoHS II EU "Directive 2011/65/EU"
- Compatible in a Pb-free or SnPb reflow environment (Z versions)
- Compliant to IPC- 9592 (September 2008), Category 2, Class I
- Compliant to REACH Directive (EC) No 1907/2006
- DOSA based
- Wide Input voltage range (4.5Vdc-14.4Vdc)
- Output voltage programmable from 0.51Vdc to 3.63Vdc via external resistor and PMBus™#
- Digital interface through the PMBus^{™#} protocol
- Tunable Loop[™] to optimize dynamic output voltage response
- Flexible output voltage sequencing EZ-SEQUENCE
- Power Good signal
- Fixed switching frequency with capability of external synchronization
- Output over current protection (non-latching)
- Over temperature protection
- Remote On/Off
- Ability to sink and source current
- Cost efficient open frame design
- Small size: 20.32 mm x 11.45 mm x 11 mm (0.8 in x 0.45 in x 0.433 in)
- Wide operating temperature range [-40°C to 85°C]
- UL* 60950-1 2nd Ed. Recognized, CSA⁺ C22.2 No. 60950-1-07 Certified, and VDE[‡] (EN60950-1 2nd Ed.) Licensed
- ISO** 9001 and ISO 14001 certified manufacturing facilities

Description

The 35A Digital MicroDLynxIITM power modules are non-isolated dc-dc converters that can deliver up to 35A of output current. These modules operate over a wide range of input voltage ($V_{IN} = 4.5$ Vdc-14.4Vdc) and provide a precisely regulated output voltage from 0.51Vdc to 3.63Vdc, programmable via an external resistor and PMBusTM control. Features include a digital interface using the PMBusTM protocol, remote On/Off, adjustable output voltage, over current and over temperature protection. The PMBusTM finterface supports a range of commands to both control and monitor the module. The module also includes the Tunable LoopTM feature that allows the user to optimize the dynamic response of the converter to match the load with reduced amount of output capacitance leading to savings on cost and PWB area.

* UL is a registered trademark of Underwriters Laboratories, Inc.

[†] CSA is a registered trademark of Canadian Standards Association

* VDE is a trademark of Verband Deutscher Elektrotechniker e.V.
 ** ISO is a registered trademark of the International Organization of Standards

The PMBus name and logo are registered trademarks of the System Management Interface Forum (SMIF)



Absolute Maximum Ratings

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. These are absolute stress ratings only, functional operation of the device is not implied at these or any other conditions in excess of those given in the operations sections of the data sheet. Exposure to absolute maximum ratings for extended periods can adversely affect the device reliability.

Parameter	Device	Symbol	Min	Max	Unit
Input Voltage	All	V _{IN}	-0.3	15	V
Continuous					
VS, ON/OFF, SEQ	All			7	V
CLK, DATA, SMBALERT#,SYNC	All		-0.3	3.6	V
Operating Ambient Temperature	All	T _A	-40	85	°C
(see Thermal Considerations section)					
Storage Temperature	All	T _{stg}	-55	125	°C

Electrical Specifications

Unless otherwise indicated, specifications apply over all operating input voltage, resistive load, and temperature conditions.

Parameter	Device	Symbol	Min	Тур	Max	Unit
Operating Input Voltage	All	V _{IN}	4.5		14.4	Vdc
Maximum Input Current	All	l _{IN,max}			33	Adc
(V _{IN} =4.5V to 14V, I _O =I _{O, max})						
Input No Load Current	V _{0,set} = 0.6 Vdc	I _{IN,No} load		43		mA
($V_{IN} = 12Vdc$, $I_0 = 0$, module enabled)	V _{O,set} = 3.63Vdc	I _{IN,No load}		106		mA
Input Stand-by Current (V _{IN} = 12Vdc, module disabled)	All	I _{IN,stand-by}		16		mA
Inrush Transient	All	l²t			1	A ² s
Input Reflected Ripple Current, peak-to-peak (5Hz to 20MHz, 1µH source impedance; V _{IN} =0 to 14V. Io= Iomax ; See Test Configurations)	All			35		mAp-p
Input Ripple Rejection (120Hz)	All			-71		dB
Output Voltage Set-point accuracy over entire output range						
0 to 85°C, Vo=over entire range	All	VO, set	-0.5		+0.5	% VO, set
-40 to 85°C, Vo=over entire range	All	VO, set	-1		+1	% VO, set
Voltage Regulation ¹						
Line Regulation	(VIN=V _{IN, min} to V _{IN, max})			3		mV
Load (IO=IO, min to IO, max) Regulation	All			5		mV

¹Worst case Line and load regulation data, all temperatures, from design verification testing as per IPC9592.

Electrical Specifications (continued)

GE

Parameter	Device	Symbo	Min	Тур	Мах	Unit
Adjustment Range (selected by an external resistor) (Some output voltages may not be possible depending on the input voltage – see Feature Descriptions Section)	All	Vo	0.6		3.63	Vdc
PMBus Adjustable Output Voltage Range	All	Vo,adj	-15	0	+10	%V _{0,set}
PMBus Output Voltage Adjustment Step Size	All			0.4		%V _{O,set}
Remote Sense Range	All				0.5	Vdc
Output Ripple and Noise on nominal output (V _{IN} =V _{IN, nom} and Io=I _{0, min} to I _{0, max} Co = 0.1µF // 8x47 µF ceramic capacitors) Peak-to-Peak (5Hz to 20MHz bandwidth)	All			17		mV _{pk-pk}
RMS (5Hz to 20MHz bandwidth)	All			3.2		mV _{rms}
External Capacitance² Without the Tunable Loop™						
$ESR \ge 1 m\Omega$	All	C _{O, max}	8x47		16×47	μF
With the Tunable Loop™						
ESR≥0.15 mΩ	All	C _{O, max}	8x47		7000	μF
ESR≥10 mΩ	All	C _{O, max}	8x47		8500	μF
Output Current (in either sink or source mode)	All	lo	0		35²	Adc
Output Current Limit Inception (Hiccup Mode) (current limit does not operate in sink mode)	All	I _{O, lim}		413		Adcmax
Output Short-Circuit Current	All	I _{O, s/c}		18		Arms
(V₀≤250mV) (Hiccup Mode)						
Efficiency	V _{0,set} = 0.6Vdc	η		80.2%		%
V _{IN} = 12Vdc, T _A =25°C	V _{0, set} = 1.2Vdc	η		87.8%		%
$I_{O}=I_{O, max}, V_{O}=V_{O,set}$	V _{O,set} = 1.8Vdc	η		91.4%		%
	V _{0,set} = 2.5Vdc	η		93.2%		%
	V _{O,set} = 3.3Vdc	η		94.3%		%
Switching Frequency	All	f _{sw}		500		kHz

² External capacitors may require using the new Tunable Loop™ feature to ensure that the module is stable as well as getting the best transient response. See the Tunable Loop™ section for details.

³ For ambient temperatures lower that -20C the minimum OCP is 30A. Monotonic start-up is guaranteed for output current 30A and below.

Electrical Specifications (continued)

Parameter	Device	Symbol	Min	Тур	Max	Unit
Frequency Synchronization	All					
Synchronization Frequency Range (2 x f _{switch})	All		950	1000	1050	kHz
High-Level Input Voltage	All	VIH	2			V
Low-Level Input Voltage	All	VIL			0.4	V
Minimum Pulse Width, SYNC	All	t _{sync}	100			ns
Maximum SYNC rise time	All	t _{sync_sh}			100	ns

General Specifications

Parameter	Device	Min	Тур	Max	Unit
Calculated MTBF (I ₀ =0.8I _{0, max} , T _A =40°C) Telecordia Issue 2 Method 1 Case 3	All		66,823,110		Hours
Weight			7.3		g (oz.)

Feature Specifications

Unless otherwise indicated, specifications apply overall operating input voltage, resistive load, and temperature conditions. See Feature Descriptions for additional information.

Parameter	Device	Symbol	Min	Тур	Max	Unit
On/Off Signal Interface						
(V_{IN}=V_{IN,min} to V_{IN,max}; open collector or equivalent,						
Signal referenced to GND)						
Device code with suffix "4" – Positive Logic (See Ordering Information)						
Logic High (Module ON)						
Input High Current	All	Ін			17	uA
Input High Voltage	All	Vih	2.1		7	V
Logic Low (Module OFF)						
Input Low Current	All	lı∟			2	uA
Input Low Voltage	All	VIL	-0.2		0.8	V
Device Code with no suffix – Negative Logic (See Ordering Information)						
(On/OFF pin is open collector/drain logic input with						
external pull-up resistor; signal referenced to GND)						
Logic High (Module OFF)						
Input High Current	All	Ін			3	mA
Input High Voltage	All	Vih	2.1		7	Vdc
Logic Low (Module ON)						
Input low Current	All	lı∟			500	μΑ
Input Low Voltage	All	VIL	0		0.8	Vdc

Feature Specifications (cont.)

Parameter	Device	Symbol	Min	Тур	Max	Units
Turn-On Delay and Rise Times						
$(V_{IN}{=}V_{IN,nom,}I_{0}{=}I_{0,max},V_{0}$ to within ±1% of steady state)						
Case 1: On/Off input is enabled and then input power is applied (delay from instant at which $V_{IN} = V_{IN, min}$ until $V_0 = 10\%$ of $V_{0, set}$)	All	Tdelay		1.2		msec
Case 2: Input power is applied for at least one second and then the On/Off input is enabled (delay from instant at which Von/Off is enabled until $V_0 = 10\%$ of $V_{0, set}$)	All	Tdelay		1.1		msec
Output voltage Rise time (time for V_0 to rise from 10% of Vo, set to 90% of Vo, set)	All	Trise		2.7		msec
Output voltage overshoot ($T_A = 25^{\circ}C$ $V_{IN} = V_{IN, min}$ to $V_{IN, max}$, $I_O = I_{O, min}$ to $I_{O, max}$) With or without maximum external capacitance					3.0	% V _{O, set}
Over Temperature Protection (See Thermal Considerations section)	All	Тот		122		°C
PMBus Over Temperature Warning Threshold *	All	Twarn		105		°C
Tracking Accuracy (Power-Up: 2V/ms)	All	Vseq –Vo			100	mV
(Power-Down: 2V/ms)	All	Vseq –Vo			200	mV
(V_{IN,min} to V_{IN,max}; I_{O,min} to I_{O,max} OV < V {\rm SEQ} < V_{O})						
Input Undervoltage Lockout						
Turn-on Threshold	All			4.25		Vdc
Turn-off Threshold	All			4.05		Vdc
Hysteresis	All			0.2		Vdc
PMBus Adjustable Input Under Voltage Lockout Thresholds	All		4		14	Vdc
Resolution of Adjustable Input Under Voltage Threshold	All		250			mV
PGOOD (Power Good)						
Signal Interface Open Drain, $V_{supply} \leq 5VDC$						
Overvoltage threshold for PGOOD ON	All			108.33		%V _{O, set}
Overvoltage threshold for PGOOD OFF	All			112.5		%V _{O, set}
Undervoltage threshold for PGOOD ON	All			91.67		%V _{O, set}
Undervoltage threshold for PGOOD OFF	All			87.5		%V _{O, set}
Pulldown resistance of PGOOD pin	All			40	70	Ω
Sink current capability into PGOOD pin	All				5	mA

* Over temperature Warning – Warning may not activate before alarm and unit may shutdown before warning

35A Digital MicroDLynxII[™]: Non-Isolated DC-DC Power Modules

4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

Digital Interface Specifications

Unless otherwise indicated, specifications apply over all operating input voltage, resistive load, and temperature conditions. See Feature Descriptions for additional information.

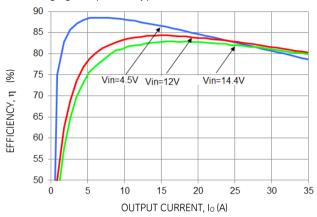
Parameter	Conditions	Symbol	Min	Тур	Max	Unit
PMBus Signal Interface Characteristics						
Input High Voltage (CLK, DATA)		Vih	2.1		3.6	V
Input Low Voltage (CLK, DATA)		VIL			0.8	V
Input high level current (CLK, DATA)		Ін	-10		10	μΑ
Input low level current (CLK, DATA)		l _{IL}	-10		10	μΑ
Output Low Voltage (CLK, DATA, SMBALERT#)	lout=2mA	Vol			0.4	V
Output high level open drain leakage current (DATA, SMBALERT#)	V _{OUT} =3.6V	I _{ОН}	0		10	μΑ
Pin capacitance		Co		0.7		pF
PMBus Operating frequency range	Slave Mode	Fрмв	10		400	kHz
Data hold time	Receive Mode Transmit Mode	thd:dat	0 300			ns
Data setup time		tsu:dat	250			ns
Measurement System Characteristics						
Output current measurement range		I _{RNG}	0		50	А
Output current measurement accuracy -40 to 85°C		I _{ACC}	-7		5	%
Temperature measurement accuracy @12Vin, 0°C to 85°C		TACC		±5*		°C
V _{out} measurement range		V _{OUT(rng)}	0		4	V
V _{OUT} measurement accuracy		Vout, acc	-2		2	%

*Accuracy as per PWM Controller Datasheet

Characteristic Curves

GE

The following figures provide typical characteristics for the 35A Digital MicroDLyn×II™ at 0.6Vo and 25°C.



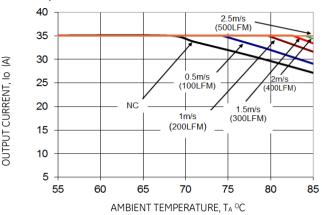


Figure 1. Converter Efficiency versus Output Current.

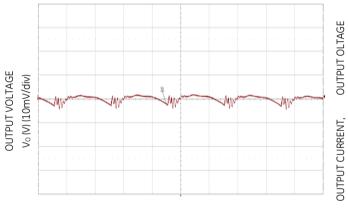


Figure 2. Derating Output Current versus Ambient Temperature and Airflow.

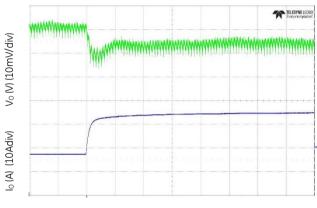
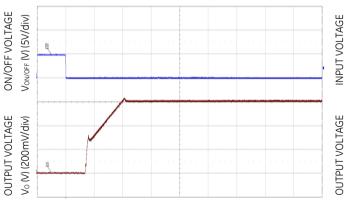




Figure 3. Typical output ripple ($C_0=8x47\mu$ F ceramic, $V_{IN}=12V$, $I_0 = I_{0,max}$,).



TIME, t (2ms/div)

TIME, t (20µs /div)

Figure 4. Transient Response to Dynamic Load Change from 50% to 100% at 12Vin, Cout=8x47uF+24x330uF, CTune=18nF, RTune=300Ω



TIME, t (2ms/div)

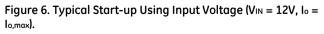
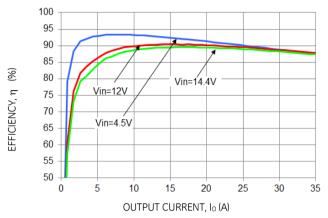
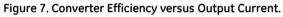


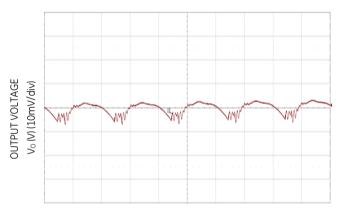
Figure 5. Typical Start-up Using On/Off Voltage (Io = Io,max).

Characteristic Curves

The following figures provide typical characteristics for the 35A Digital MicroDLyn×II™ at 1.2Vo and 25°C.

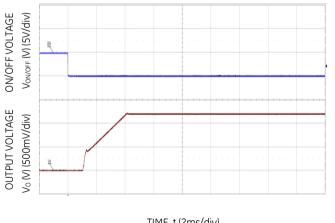






TIME, t (1µs/div)

Figure 9. Typical output ripple ($C_0=8x47\mu$ F ceramic, $V_{IN}=12V$, $I_0 = I_{0,max_i}$).



TIME, t (2ms/div)

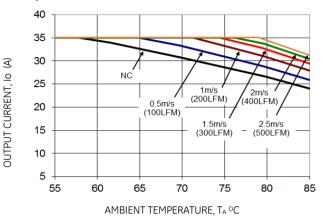
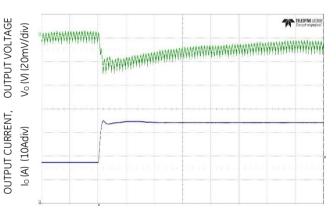
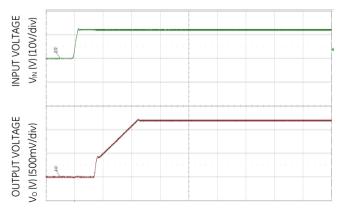


Figure 8. Derating Output Current versus Ambient Temperature and Airflow.



TIME, t (20µs /div)

Figure 10. Transient Response to Dynamic Load Change from 50% to 100% at 12Vin, Cout=8x47uF+14x330uF, CTune=10nF, RTune=300Ω



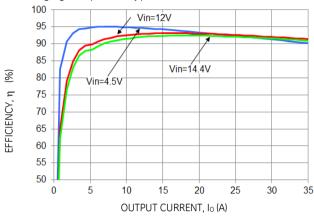
TIME, t (2ms/div)

Figure 11. Typical Start-up Using On/Off Voltage (Io = Io,max).

Figure 12. Typical Start-up Using Input Voltage (VIN = 12V, Io = lo,max).

Characteristic Curves

The following figures provide typical characteristics for the 35A Digital MicroDLynxII[™] at 1.8Vo and 25°C.



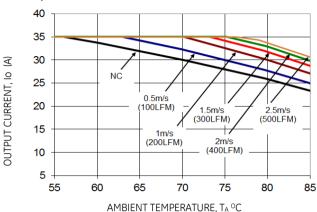
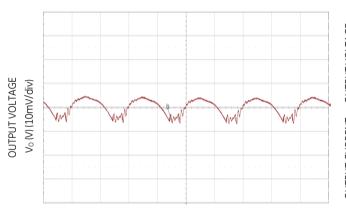
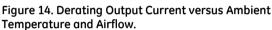


Figure 13. Converter Efficiency versus Output Current.





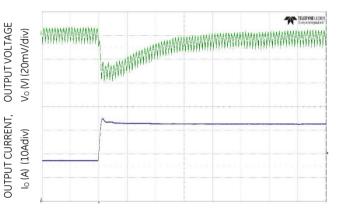




Figure 15. Typical output ripple and noise (Co=8x47µF ceramic,

 $\label{eq:TIME,t} $$TIME,t$ (20 \mu s / div)$$Figure 16. Transient Response to Dynamic Load Change from 50% to 100% at 12Vin, Cout=8x47uF+7x330uF, CTune=4.7nF, $$TURE The second statement of the s$



TIME, t (2ms/div)

Figure 17. Typical Start-up Using On/Off Voltage (Io = Io,max).



Figure 18. Typical Start-up Using Input Voltage (ViN = 12V, I_o = I_{o,max}).

VIN = 12V, Io = Io,max,).

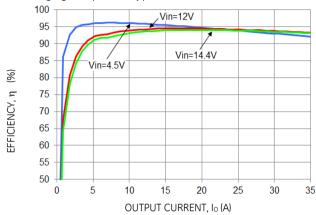
ON/OFF VOLTAGE Von/OFF (V) 5V/div)

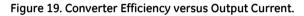
DUTPUT VOLTAGE

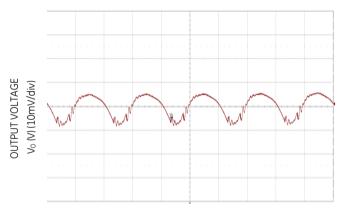
Vo (V) (1V/div)

Characteristic Curves

The following figures provide typical characteristics for the 35A Digital MicroDLynxII[™] at 2.5Vo and 25°C.

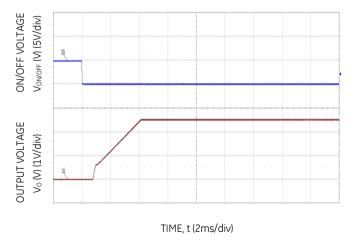






TIME, t (1µs/div)

Figure 21. Typical output ripple and noise (C_0=8x47 μ F ceramic, V_IN = 12V, I_0 = I_{0,max},).





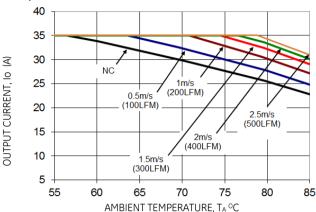


Figure 20. Derating Output Current versus Ambient Temperature and Airflow.

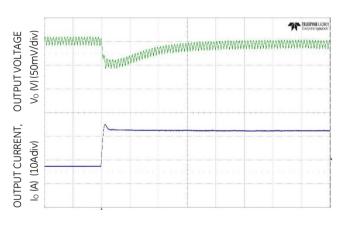




Figure 22. Transient Response to Dynamic Load Change from 50% to 100% at 12Vin, Cout=8x47uF+4x330uF, CTune=3300pF, RTune=221 Ω



TIME, t (2ms/div)

Figure 24. Typical Start-up Using Input Voltage (ViN = 12V, $I_{\rm O}$ = $I_{\rm O,max}$).

40

35

30

25

20

15

10

5

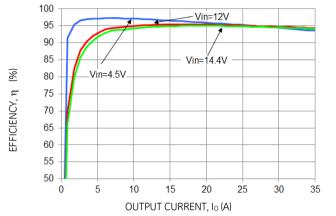
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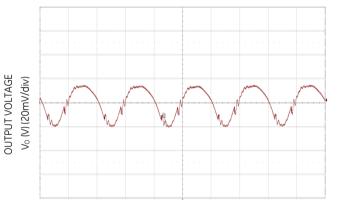
OUTPUT CURRENT, IO

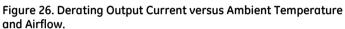
Characteristic Curves



The following figures provide typical characteristics for the 35A Digital MicroDLyn×II™ at 3.3Vo and 25°C.







65

AMBIENT TEMPERATURE, TA °C

0.5m/s (100LFM)

1.0m/s (200LFM)

70

1.5m/s (300LFM)

2.0m/s (400LFM)

75

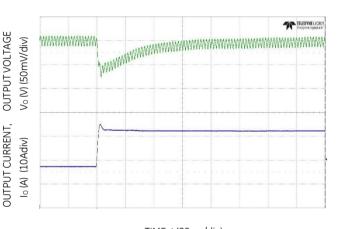
2.5m/s (500LFM)

80

85

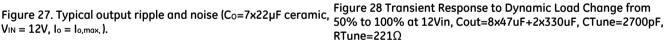
NC

60





TIME, t (20µs /div)

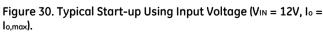




TIME, t (2ms/div)

TIME, t (2ms/div)

Figure 29. Typical Start-up Using On/Off Voltage (Io = Io,max).



ON/OFF VOLTAGE Voworf (V) (5V/div)

OUTPUT VOLTAGE

Vo (V) (1V/div)

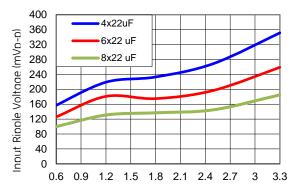
Design Considerations

Input Filtering

GF

The 35A Digital MicroDLynxII[™] module should be connected to a low ac-impedance source. A highly inductive source can affect the stability of the module. An input capacitance must be placed directly adjacent to the input pin of the module, to minimize input ripple voltage and ensure module stability.

To minimize input voltage ripple, ceramic capacitors are recommended at the input of the module. Figure 31 shows the input ripple voltage for various output voltages at 35A of load current with 4x22 μ F, 6x22 μ F or 8x22 μ F ceramic capacitors and an input of 12V.



Output Voltage (Vdc)

Figure 31. Input ripple voltage for various output voltages with $4x22 \mu$ F, $6x22 \mu$ F or $8x22 \mu$ F ceramic capacitors at the input (35A load). Input voltage is 12V.

Output Filtering

These modules are designed for low output ripple voltage and will meet the maximum output ripple specification with 0.1 μ F ceramic and 2x47 μ F ceramic capacitors at the output of the module. However, additional output filtering may be required by the system designer for a number of reasons. First, there may be a need to further reduce the output ripple and noise of the module. Second, the dynamic response characteristics may need to be customized to a particular load step change.

To reduce the output ripple and improve the dynamic response to a step load change, additional capacitance at the output can be used. Low ESR polymer and ceramic capacitors are recommended to improve the dynamic response of the module. Figure 32 provides output ripple information for different external capacitance values at various Vo and a full load current of 35A. For stable operation of the module, limit the capacitance to less than the maximum output capacitance as specified in the electrical specification table. Optimal performance of the module can be achieved by using the Tunable Loop[™] feature described later in this data sheet.

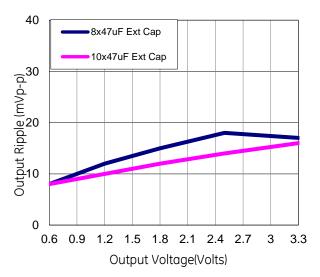


Figure 32. Output ripple voltage for various output voltages with external 8x47 μF or 10x47 μF ceramic capacitors at the output (35A load). Input voltage is 12V.

Safety Considerations

For safety agency approval the power module must be installed in compliance with the spacing and separation requirements of the end-use safety agency standards, i.e., ANSI/UL 60950-1 2nd Revised October 14, 2014, CSA C22.2 No. 60950-1-07, Second Ed. + A2:2014 (MOD), DIN EN 60950-1:2006 + A11:2009 + A1:2010 + A12:2011, + A2:2013 (VDE0805 Teil 1: 2014-08)(pending).

For the converter output to be considered meeting the requirements of safety extra-low voltage (SELV), the input must meet SELV requirements. The power module has extra-low voltage (ELV) outputs when all inputs are ELV. An external 40A 461 series Littelfuse fuse model or equivalent is recommended on the ungrounded input lead when the input voltage exceeds 8V. For input voltages less than 8V, 2 parallel 25A 456 series Littelfuse or equivalent are recommended on the ungrounded input lead.

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Analog Feature Descriptions

Remote On/Off

The module can be turned ON and OFF either by using the ON/OFF pin (Analog interface) or through the PMBus interface (Digital). The module can be configured in a number of ways through the PMBus interface to react to the two ON/OFF inputs:

- Module ON/OFF can be controlled only through the analog interface (digital interface ON/OFF commands are ignored)
- Module ON/OFF can be controlled only through the PMBus interface (analog interface is ignored)
- Module ON/OFF can be controlled by either the analog or digital interface

The default state of the module (as shipped from the factory) is to be controlled by the analog interface only. If the digital interface is to be enabled, or the module is to be controlled only through the digital interface, this change must be made through the PMBus. These changes can be made and written to non-volatile memory on the module so that it is remembered for subsequent use.

Analog On/Off

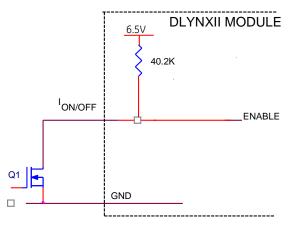
The 35A Digital MicroDLynxII[™] power modules feature an On/Off pin for remote On/Off operation. Two On/Off logic options are available. In the Positive Logic On/Off option, (device code suffix "4" – see Ordering Information), the module turns ON during a logic High on the On/Off pin and turns OFF during a logic Low. With the Negative Logic On/Off option, (no device code suffix, see Ordering Information), the module turns OFF during logic High and ON during logic Low. The On/Off signal should be always referenced to ground. For either On/Off logic option, leaving the On/Off pin disconnected will turn the module ON when input voltage is present.

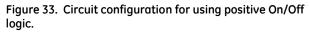
For positive logic modules, the circuit configuration for using the On/Off pin is shown in Figure 33. When the external transistor Q1 is in the OFF state, the internal PWM #Enable is pulled up internally, thus turning the module ON. When transistor Q1 is turned ON, the On/Off pin is pulled low, and consequently the internal PWM Enable signal is pulled low and the module is OFF.

For negative logic On/Off modules, the circuit configuration is shown in Fig. 34. The On/Off pin should be pulled high with an external pull-up resistor. When transistor Q2 is in the OFF state, the On/Off pin is pulled high, which pulls the internal ENABLE# High and the module is OFF. To turn the module ON, Q2 is turned ON pulling the On/Off pin low resulting in the PWM ENABLE# pin going Low. The maximum voltage allowed on the On/Off pin is 7V. If Vin is used as a source, then a suitable external resistor R1 must be used to ensure that the voltage on the On/Off pin does not exceed 7V

Digital On/Off

Please see the Digital Feature Descriptions section.





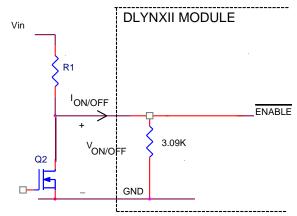


Figure 34. Circuit configuration for using negative On/Off logic.

Monotonic Start-up and Shutdown

The module has monotonic start-up and shutdown behavior for any combination of rated input voltage, output current and operating temperature range.

Startup into Pre-biased Output

The module can start into a prebiased output as long as the prebias voltage is 0.5V less than the set output voltage.

Analog Output Voltage Programming

The output voltage of the module is programmable to any voltage from 0.6dc to 3.63Vdc by connecting a resistor between the Trim and SIG_GND pins of the module. Certain restrictions apply on the output voltage set point depending on the input voltage. These are shown in the Output Voltage vs. Input Voltage Set Point Area plot in Fig. 35. The Upper Limit curve shows that for output voltages lower than 1V, the input voltage must be lower than the maximum of 14.4V. The Lower Limit curve shows that for output voltages

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higher than 0.6V, the input voltage needs to be larger than the minimum of 4.5V. At output voltage of 2.5V, the input voltage should not be below 5Vin and at output voltage of 3.3V the input voltage should be at least 6Vin.

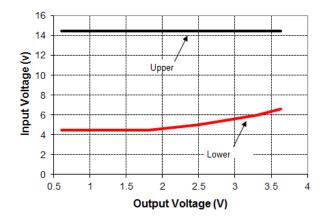
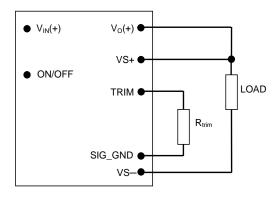


Figure 35. Output Voltage vs. Input Voltage Set Point Area plot showing limits where the output voltage can be set for different input voltages.



Caution – Do not connect SIG_GND to GND elsewhere in the layout

Figure 36. Circuit configuration for programming output voltage using an external resistor.

Without an external resistor between Trim and SIG_GND pins, the output of the module will be 0.6Vdc. To calculate the value of the trim resistor, *Rtrim* for a desired output voltage, should be as per the following equation:

$$Rtrim = \left[\frac{12}{(Vo - 0.6)}\right] k \Omega$$

Rtrim is the external resistor in $k\Omega$

Vo is the desired output voltage.

Table 1 provides Rtrim values required for some common output voltages.

Table 1

V _{O, set} (V)	Rtrim (KΩ)
0.6	Open
0.9	40
1.0	30
1.2	20
1.5	13.33
1.8	10
2.5	6.316
3.3	4.444

Digital Output Voltage Adjustment

Please see the Digital Feature Descriptions section.

Remote Sense

The power module has a Remote Sense feature to minimize the effects of distribution losses by regulating the voltage between the sense pins (VS+ and VS-). The voltage drop between the sense pins and the VOUT and GND pins of the module should not exceed 0.5V.

Analog Voltage Margining

Output voltage margining can be implemented in the module by connecting a resistor, R_{margin-up}, from the Trim pin to the ground pin for margining-up the output voltage and by connecting a resistor, R_{margin-down}, from the Trim pin to output pin for margining-down. Figure 37 shows the circuit configuration for output voltage margining. The POL Programming Tool or Power Module Wizard(PMW), available at www.gecriticalpower.com under the Downloads section, also calculates the values of R_{margin-up} and R_{margin-down} for a specific output voltage and % margin. Please consult your local GE technical representative for additional details.

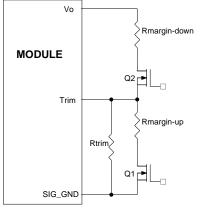


Figure 37. Circuit Configuration for margining Output voltage.

Digital Output Voltage Margining

Please see the Digital Feature Descriptions section.

Output Voltage Sequencing

The power module includes a sequencing feature, EZ-SEQUENCE that enables users to implement various types of output voltage sequencing in their applications. This is accomplished via an additional sequencing pin. When not using the sequencing feature, leave it unconnected.

When an analog voltage is applied to the SEQ pin, the output voltage tracks this voltage until the output reaches the set-point voltage. The final value of the SEQ voltage must be set higher than the set-point voltage of the module. The output voltage follows the voltage on the SEQ pin on a one-to-one basis. By connecting multiple modules together, multiple modules can track their output voltages to the voltage applied on the SEQ pin.

For proper voltage sequencing, first, input voltage is applied to the module. The On/Off pin of the module is left unconnected (or tied to GND for negative logic modules or tied to V_{IN} for positive logic modules) so that the module is ON by default. After applying input voltage to the module, a minimum 10msec delay is required before applying voltage on the SEQ pin. This delay gives the module enough time to complete its internal power-up soft-start cycle. During the delay time, the SEQ pin should be held close to ground (nominally 50mV \pm 20 mV). This is required to keep the internal op-amp out of saturation thus preventing output overshoot during the start of the sequencing ramp. By selecting resistor R1 (see fig. 38) according to the following equation

$$R1 = \frac{26150}{6.5 - 0.05} = 4052 \text{ ohms, } (4.02 \text{K Std.})$$

the voltage at the sequencing pin will be 50mV when the sequencing signal is at zero.

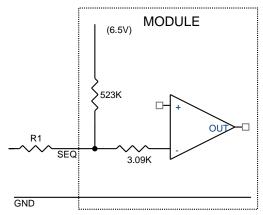


Figure 38. Circuit showing connection of the sequencing signal to the SEQ pin.

After the 10msec delay, an analog voltage is applied to the SEQ pin and the output voltage of the module will track this voltage on a one-to-one volt bases until the output reaches the set-point voltage. To initiate simultaneous shutdown of the modules, the SEQ pin voltage is lowered in a controlled manner. The output voltage of the modules tracks the voltages below their set-point voltages on a one-to-one basis. A valid input voltage must be maintained until the tracking and output voltages reach ground potential.

When using the EZ-SEQUENCE[™] feature to control start-up of the module, pre-bias immunity during start-up is disabled. The pre-bias immunity feature of the module relies on the module being in the diode-mode during start-up. When using the EZ-SEQUENCE[™] feature, modules goes through an internal set-up time of 10msec, and will be in synchronous rectification mode when the voltage at the SEO pin is applied. This will result in the module sinking current if a pre-bias voltage is present at the output of the module. When prebias immunity during start-up is required, the EZ-SEQUENCE[™] feature must be disabled. For additional guidelines on using the EZ-SEQUENCE[™] feature please refer to Application Note AN04-008 "Application Guidelines for Non-Isolated Converters: Guidelines for Sequencing of Multiple Modules", or contact the GE technical representative for additional information.

Overcurrent Protection

To provide protection in a fault (output overload) condition, the unit is equipped with internal current-limiting circuitry and can endure current limiting continuously. At the point of current-limit inception, the unit enters hiccup mode. The unit operates normally once the output current is brought back into its specified range.

Digital Adjustable Overcurrent Warning

Please see the Digital Feature Descriptions section.

Overtemperature Protection

To provide protection in a fault condition, the unit is equipped with a thermal shutdown circuit. The unit will shut down if the over-temperature threshold of 122 (typ) is exceeded at the thermal reference point T_{ref} . Please refer to Electrical characteristic table, over-temperature section on page 5. Once the unit goes into thermal shutdown it will then wait to cool before attempting to restart.

Digital Temperature Status via PMBus

Please see the Digital Feature Descriptions section.

Digitally Adjustable Output Over and Under Voltage Protection

Please see the Digital Feature Descriptions section.

Input Undervoltage Lockout

At input voltages below the input undervoltage lockout limit, the module operation is disabled. The module will begin to operate at an input voltage above the undervoltage lockout turn-on threshold.

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Digitally Adjustable Input Undervoltage Lockout Please see the Digital Feature Descriptions section. Digitally Adjustable Power Good Thresholds

Please see the Digital Feature Descriptions section.

Synchronization

The module switching frequency can be synchronized to a signal with an external frequency within a specified range. Synchronization can be done by using the external signal applied to the SYNC pin of the module as shown in Fig. 39, with the converter being synchronized by the rising edge of the external signal. The Module switches at half the SYNC frequency. The Electrical Specifications table specifies the requirements of the external SYNC signal. If the SYNC pin is not used, the module will free run at the default switching frequency. **If synchronization is not being used, connect the SYNC pin to SIG_GND**.

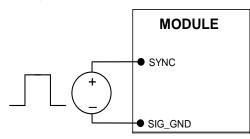


Figure 39. External source connections to synchronize switching frequency of the module.

Measuring Output Current, Output Voltage and Temperature

Please see the Digital Feature Descriptions section.

Dual Layout

Identical dimensions and pin layout of Analog and Digital MicroDLynxII modules permit migration from one to the other without needing to change the layout. In both cases the trim resistor is connected between trim and signal ground. The output of the analog module cannot be trimmed down to 0.51V

Tunable Loop™

The module has a feature that optimizes transient response of the module called Tunable $Loop^{TM}$.

External capacitors are usually added to the output of the module for two reasons: to reduce output ripple and noise (see Figure 38) and to reduce output voltage deviations from the steady-state value in the presence of dynamic load current changes. Adding external capacitance however affects the voltage control loop of the module, typically causing the loop to slow down with sluggish response. Larger values of external capacitance could also cause the module to become unstable.

The Tunable ${\rm Loop}^{\rm TM}$ allows the user to externally adjust the voltage control loop to match the filter network connected to

the output of the module. The Tunable $Loop^{TM}$ is implemented by connecting a series R-C between the VS+ and TRIM pins of the module, as shown in Fig. 40. This R-C allows the user to externally adjust the voltage loop feedback compensation of the module.

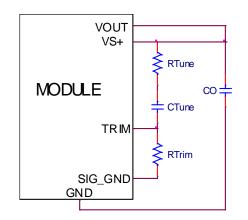


Figure. 40. Circuit diagram showing connection of R_{TUME} and C_{TUNE} to tune the control loop of the module.

Recommended values of R_{TUNE} and C_{TUNE} for different output capacitor combinations are given in Tables 2 and 3. Table 3 shows the recommended values of R_{TUNE} and C_{TUNE} for different values of ceramic output capacitors up to 1000uF that might be needed for an application to meet output ripple and noise requirements. Selecting R_{TUNE} and C_{TUNE} according to Table 3 will ensure stable operation of the module.

In applications with tight output voltage limits in the presence of dynamic current loading, additional output capacitance will be required. Table 3 lists recommended values of R_{TUNE} and C_{TUNE} in order to meet 2% output voltage deviation limits for some common output voltages in the presence of a 10A to 35A step change (50% of full load), with an input voltage of 12V.

Please contact your GE technical representative to obtain more details of this feature as well as for guidelines on how to select the right value of external R-C to tune the module for best transient performance and stable operation for other output capacitance values.

Table 2. General recommended values of of RTUNE and
C _{TUNE} for Vin=12V and various external ceramic capacitor
combinations.

Со	16x47µF	20x47µF	24x47µF	30x47µF	40x47µF
R _{TUNE}	300	300	300	300	300
CTUNE	470pF	560pF	680pF	820pF	1.2nF

Table 3. Recommended values of R_{TUNE} and C_{TUNE} to obtain transient deviation of 2% of Vout for a 10A step load with Vin=12V.

Vo	3.3V	2.5V	1.8V	1.2V	0.6V
Co	8x47uF + 2x330uF	8x47uF + 4x330uF	8x47uF + 7x330uF	8x47uF + 14x330uF	8x47uF + 24x330uF
R _{TUNE}	221Ω	221Ω	221Ω	300Ω	300Ω
C _{TUNE}	2700pF	3300pF	4700pF	10nF	18nF
ΔV	50mV	43mV	32mV	18mV	12mV

Note: The capacitors used in the Tunable Loop tables are 47 $\mu\text{F/3}$ m Ω ESR ceramic and 330 $\mu\text{F/12}$ m Ω ESR polymer capacitors.

Power Module Wizard

GE offers a free web based easy to use tool that helps users simulate the Tunable Loop performance of the UJT035. Go to <u>http://ge.transim.com/pmd/Home</u> and sign up for a free account and use the module selector tool. The tool also offers downloadable Simplis/Simetrix models that can be used to assess transient performance, module stability, etc.

Digital Feature Descriptions

PMBus Interface Capability

GF

The 35A Digital MicroDLynxII[™] power modules have a PMBus interface that supports both communication and control. The PMBus Power Management Protocol Specification can be obtained from <u>www.pmbus.org</u>. The modules support a subset of version 1.1 of the specification (see Table 6 for a list of the specific commands supported). Most module parameters can be programmed using PMBus and stored as defaults for later use.

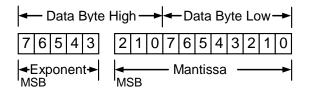
All communication over the module PMBus interface must support the Packet Error Checking (PEC) scheme. The PMBus master must generate the correct PEC byte for all transactions, and check the PEC byte returned by the module.

The module also supports the SMBALERT# response protocol whereby the module can alert the bus master if it wants to talk. For more information on the SMBus alert response protocol, see the System Management Bus (SMBus) specification.

The module has non-volatile memory that is used to store configuration settings. Not all settings programmed into the device are automatically saved into this non-volatile memory, only those specifically identified as capable of being stored can be saved (see Table 6 for which command parameters can be saved to non-volatile storage).

PMBus Data Format

For commands that set thresholds, voltages or report such quantities, the module supports the "Linear" data format among the three data formats supported by PMBus. The Linear Data Format is a two byte value with an 11-bit, two's complement mantissa and a 5-bit, two's complement exponent. The format of the two data bytes is shown below:



The value is of the number is then given by

Value = Mantissa x 2 Exponent

PMBus Addressing

The power module can be addressed through the PMBus using a device address. The module has 64 possible addresses (0 to 63 in decimal) which can be set using resistors connected from the ADDR0 and ADDR1 pins to GND. Note that some of these addresses (0, 1, 2, 3, 4, 5, 6, 7, 8, 9, 10, 11 12, 40, 44, 45, 55 in decimal) are reserved according to the SMBus specifications and may not be useable. The address is set in the form of two octal (0 to 7) digits, with each pin setting one digit. The ADDR1 pin sets the high order digit and ADDR0 sets the low order digit. The resistor values suggested for each digit are shown in Table 4 (1% tolerance resistors are recommended). Note that if either address resistor value is outside the range specified in Table 4, the module will respond to address 127.

I dble 4			
Digit Resistor Value (KΩ)			
0	11		
1	18.7		
2	27.4		
3	38.3		
4	53.6		
5	82.5		
6	127		
7	187		

The user must know which I²C addresses are reserved in a system for special functions and set the address of the module to avoid interfering with other system operations. Both 100kHz and 400kHz bus speeds are supported by the module. Connection for the PMBus interface should follow the High Power DC specifications given in section 3.1.3 in the SMBus specification V2.0 for the 400kHz bus speed or the Low Power DC specifications in section 3.1.2. The complete SMBus specification is available from the SMBus web site, <u>smbus.org</u>.

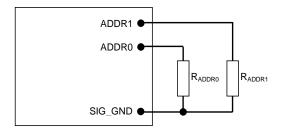


Figure 41. Circuit showing connection of resistors used to set the PMBus address of the module.

Operation (01h)

This is a paged register. The OPERATION command can be use to turn the module on or off in conjunction with the ON/OFF pin input. It is also used to margin up or margin down the output voltage

PMBus Enabled On/Off

The module can also be turned on and off via the PMBus interface. The OPERATION command is used to actually turn the module on and off via the PMBus, while the ON_OFF_CONFIG command configures the combination of analog ON/OFF pin input and PMBus commands needed to turn the module on and off. Bit [7] in the OPERATION command data byte enables the module, with the following functions:

- 0 : Output is disabled
- 1 : Output is enabled

This module uses the lower five bits of the ON_OFF_CONFIG data byte to set various ON/OFF options as follows:

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Bit Position	4	3	2	1	0
Access	r/w	r/w	r/w	r/w	r
Function	PU	CMD	CPR	POL	CPA
Default Value	1	0	1	1	0

PU: Sets the default to either operate any time input power is present or for the ON/OFF to be controlled by the analog ON/OFF input and the PMBus OPERATION command. This bit is used together with the CP, CMD and ON bits to determine startup.

Bit Value	Action
0	Module powers up any time power is present regardless of state of the analog ON/OFF pin
1	Module does not power up until commanded by the analog ON/OFF pin and the OPERATION command as programmed in bits [2:0] of the ON_OFF_CONFIG register.

CMD: The CMD bit controls how the device responds to the OPERATION command.

Bit Value	Action
0	Module ignores the ON bit in the OPERATION command
1	Module responds to the ON bit in the OPERATION command

CPR: Sets the response of the analog ON/OFF pin. This bit is used together with the CMD, PU and ON bits to determine startup.

Bit Value	Action
0	Module ignores the analog ON/OFF pin, i.e. ON/OFF is only controlled through the PMBUS via the OPERATION command
1	Module requires the analog ON/OFF pin to be asserted to start the unit

CPA: Sets the action of the analog ON/OFF pin when turning the controller OFF. This bit is internally read and cannot be modified by the user

PMBus Adjustable Soft Start Rise Time

The soft start rise time can be adjusted in the module via PMBus. When setting this parameter, make sure that the charging current for output capacitors can be delivered by the module in addition to any load current to avoid nuisance tripping of the overcurrent protection circuitry during startup. The TON_RISE command sets the rise time in ms, and allows choosing soft start times between 600µs and 9ms, with possible values listed in Table 5. Note that the exponent is fixed at -4 (decimal) and the upper two bits of the mantissa are also fixed at 0.

Table 5

Rise Time	Exponent	Mantissa
600µs	11100	0000001010
900µs	11100	0000001110
1.2ms	11100	00000010011
1.8ms	11100	00000011101
2.7ms	11100	00000101011
4.2ms	11100	00001000011
6.0ms	11100	00001100000
9.0ms	11100	00010010000

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Output Voltage Adjustment Using the PMBus

The VREF_TRIM parameter is important for a number of PMBus commands related to output voltage trimming, and margining. Each of the 2 output voltages of the module can be set as the combination of the voltage divider formed by RTrim and a $20k\Omega$ upper divider resistor inside the module, and the internal reference voltage of the module. The reference voltage VREF is be nominally set at 600mV, and the output regulation voltage is then given by:

$$V_{OUT} = \left[\frac{20000 + RTrim}{RTrim}\right] \times V_{REF}$$

Hence the module output voltage is dependent on the value of RTrim which is connected external to the module.

The VREF TRIM parameter is used to apply a fixed offset voltage to the reference voltage can be specified using the "Linear" format and two bytes. The exponent is fixed at -9 (decimal). The resolution of the adjustment is 7 bits, with a resulting step size of approximately 0.4%. The maximum trim range is -20% to +10% of the nominal reference voltage(600mV) in 2mV steps. Possible values range from -120mV to +60mV. The exception is at 0.6Vout where the allowable trim range is only -90mV to +60mV to prevent the module from operating at lower than 0.51Vdc. When trimming the voltage below 0.6V, the module max. input voltage operating point also reduces proportionally. As shown earlier in Fig.41, the maximum permissible input voltage is 13V. For any voltage trimmed below 0.6V, the maximum input voltage will have to be reduced by the same factor.

When PMBus commands are used to trim or margin the output voltage, the value of V_{REF} is what is changed inside the module, which in turn changes the regulated output voltage of the module.

The nominal output voltage of the module is adjustable with a minimum step size of 0.4% over a +10% to -20% range from nominal using the VREF_TRIM command over the PMBus.

The VREF_TRIM command can be used to apply a fixed offset voltage to either of the output voltage command value using the "Linear" mode with the exponent fixed at -9 (decimal). The value of the offset voltage is given by

$$V_{REF(offset)} = VREF _TRIM \times 2^{-9}$$

This offset voltage is added to the voltage set through the divider ratio and nominal V_{REF} to produce the trimmed output voltage. If a value outside of the +10%/-20% adjustment range is given with this command, the module will set it's output voltage to the upper or lower limit value (as if VOUT_TRIM, assert SMBALRT#, set the CML bit in STATUS_BYTE and the invalid data bit in STATUS_CML.

Applications Example

For a design where the output voltage is 1.8V and the output needs to be trimmed down by 20mV.

• The internal reference voltage is 0.6V. So we need to determine how the 20mV translates to a change in the internal reference voltage.

- Divider Ratio = Vref/Vout = 0.6/1.8 = 0.33
- Hence a 20mV change at 1.8Vo requires a 0.33x20mV = 6.6mV change in the reference voltage.
- Vref(offset) = (6.6)/1000 = 0.0066 Volts (- sign since we are trimming down)
- V_{ref(offset)} = V_{ref_Trim} x 2 ⁻⁹
- Vref_Trim = Vref(offset) x 512
- V_{ref_Trim} = -0.0066 × 512 = -3.3 = -3 (rounded to nearest integer

Output Voltage Margining Using the PMBus

The module can also have its output margined via PMBus commands. The command STEP_VREF_MARGIN_HIGH will set the margin high voltage, while the command STEP_VREF_MARGIN_LOW sets the margin low voltage. Both the STEP_VREF_MARGIN_LOW commands will use the "Linear" mode with the exponent fixed at –9 (decimal). Two bytes are used for the mantissa with the upper bit [7] of the high byte fixed at 0. The actual margined output voltage is a combination of the STEP_VREF_MARGIN_LOW and the VREF_TRIM values as shown below. The net permissible voltage range change is - 30% to +10% for the margin high command and -20% to 0% for the margin low command

$V_{REF(MH)} =$

$(STEP_VREF_MARGIN_HIGH+VREF_TRIM) \times 2^{-9}$ Applications Example

For a design where the output voltage is 1.2V and the output needs to be trimmed up by 100mV (within 10% of Vo). • The internal reference voltage is 0.6V. So we need to determine how the 100mV translates to a change in the internal reference voltage.

- Divider Ratio = Vref/Vout = 0.6/1.2 = 0.5
- Hence a 100mV change at 1.2Vo requires a 0.5x100mV = 50mV change in the reference voltage.
- V_{REF(MH)} = (50)/1000 = 0.05 Volts
- VREF(MH) = (Step_Vref_margin_high + Vref_trim) x 2 -9
- Assume V_{ref_Trim} = 0 here
- Step_V_{ref_margin_high} = V_{REF(MH)} x 512
- Step_V_{ref_margin_high} = 0.05 × 25.6 = 26 (rounded to nearest integer

$V_{REF(ML)} =$

$(STEP _VREF _MARGIN _LOW + VREF _TRIM) \times 2^{-9}$ Applications Example

For a design where the output voltage is 1.8V and the output needs to be trimmed down by 100mV (within -20% of Vo). • The internal reference voltage is 0.6V. So we need to determine how the 100mV translates to a change in the internal reference voltage.

- Divider Ratio = Vref/Vout = 0.6/1.8 = 0.33
- Hence a 100mV change at 1.2Vo requires a 0.33×100mV = 33mV change in the reference voltage.
- $V_{\text{REF(MH)}} = -(33)/1000 = -0.033$ Volts (- sign since we are margining down)

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- VREF(ML) = (Step_Vref_margin_low + Vref_trim) x 2 -9
- Assume V_{ref_Trim} = 3 here (from V _{Ref_Trim} example earlier)
- Step_Vref_margin_low = VREF(ML) x 512 Vref_trim
- Step_V_{ref_margin_low} = -0.033 × 512 (-3) = -16.9+3 = -13.9 = -14 (rounded to nearest integer

The module will support the margined high or low voltages using the OPERATION command. Bits [5:2] are used to enable margining as follows:

•	00XX	:	Margin Off
•	0101	:	Margin Low (Act on

- 0101 : Margin Low (Act on Fault)
 0110 : Margin Low (Act on Fault)
- 1001 : Margin Low (Act on Fault)
- 1001 : Hargin High (Act of Fault)
 1010 : Margin High (Act of Fault)

PMBus Adjustable Overcurrent Warning

The module can provide an overcurrent warning via the PMBus. The threshold for the overcurrent warning can be set using the parameter IOUT_OC_WARN_LIMIT. This command uses the "Linear" data format with a two byte data word where the upper five bits [7:3] of the high byte represent the exponent and the remaining three bits of the high byte [2:0] and the eight bits in the low byte represent the mantissa. The exponent is fixed at –1 (decimal). The upper five bits of the mantissa are fixed at 0 while the lower six bits are programmable with a default value of 37A (decimal). The resolution of this warning limit is 500mA. The value of the IOUT_OC_WARN_LIMIT can be stored to non-volatile memory using the STORE_DEFAULT_ALL command

Temperature Status via PMBus

The module will provide information related to temperature of the module through the READ_TEMPERATURE_2 command. The command returns external temperature in degrees Celsius. This command will use the "Linear" data format with a two byte data word where the upper five bits [7:3] of the high byte will represent the exponent and the remaining three bits of the high byte [2:0] and the eight bits in the low byte will represent the mantissa. The exponent is fixed at 0 (decimal). The lower 11 bits are the result of the ADC conversion of the external temperature

PMBus Adjustable Output Over, Under Voltage Protection and Power Good

The module has a common command to set the PGOOD, VOUT_UNDER_VOLTAGE(UV) and VOUT_OVER_VOLTAGE (OV) limits as a percentage of nominal. Refer to Table 6 of the next section for the available settings. The PMBus command VOUT_OVER_VOLTAGE (OV) is used to set the output over voltage threshold from two possible values: +12.5% or +16.67% of the commanded output voltage for each output.

The module provides a Power Good (PGOOD) that is implemented with an open-drain output to indicate that the output voltage is within the regulation limits of the power module. The PGOOD signal is de-asserted to a low state if any condition such as overtemperature, overcurrent or loss of regulation occurs that would result in the output voltage going outside the specified thresholds. The PGOOD thresholds are user selectable via the PMBus (the default values are as shown in the Feature Specifications Section). Each threshold is set up symmetrically above and below the nominal value. The PGL (POWERGOODLOW) command will set the output voltage level above which PGOOD is asserted (lower threshold). The PGH(POWERGOODHIGH) command will set the level above which the PGOOD command is deasserted. This command will also set two thresholds symmetrically placed around the nominal output voltage. Normally, the PGL threshold is set higher than the PGH threshold.

The PGOOD terminal can be connected through a pullup resistor (suggested value $100K\Omega$) to a source of 5VDC or lower. The current through the PGood terminal should be limited to a max value of 5mA

PMBus Adjustable Input Undervoltage Lockout

The module allows for adjustment of the input under voltage lockout and hysteresis. The command VIN_ON allows setting the input voltage turn on threshold for each output, while the VIN_OFF command will set the input voltage turn off threshold. For the VIN_ON command, possible values are 4.25V to 16V in variable steps. For the VIN_OFF command, possible values are 4V to 15.75V in 0.5V steps. If other values are entered for either command, they is mapped to the closest of the allowed values.

Both the VIN_ON and VIN_OFF commands use the "Linear" format with two data bytes. The upper five bits will represent the exponent (fixed at -2) and the remaining 11 bits will represent the mantissa. For the mantissa, the four most significant bits are fixed at 0.

Measurement of Output Current and Voltage

The module is capable of measuring key module parameters such as output current and voltage and providing this information through the PMBus interface.

Measuring Output Current Using the PMBus

The module measures current by using the inductor winding resistance as a current sense element. The inductor winding resistance is then the current gain factor used to scale the measured voltage into a current reading. This gain factor is the argument of the IOUT_CAL_GAIN command, and consists of two bytes in the linear data format. The exponent uses the upper five bits [7:3] of the high data byte in two-s complement format and is fixed at –4 (decimal). The remaining 11 bits in two's complement binary format represent the mantissa. During manufacture, each module is calibrated by measuring and storing the current gain factor into non-volatile storage. DONOT CHANGE THE FACTORY PROGRAMMED VALUE.

The current measurement accuracy is also improved by each module being calibrated during manufacture with the offset in the current reading. The IOUT_CAL_OFFSET command is used to store and read the current offset. The argument for this command consists of two bytes composed of a 5-bit exponent (fixed at -4d) and a 11-bit

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mantissa. This command has a resolution of 62.5mA and a range of -4000mA to +3937.5mA. DONOT CHANGE THE FACTORY PROGRAMMED VALUE.

The READ_IOUT command provides module average output current information. This command only supports positive or current sourced from the module. If the converter is sinking current a reading of 0 is provided. The READ_IOUT command returns two bytes of data in the linear data format. The resolution of the command is 62.5mA. The exponent uses the upper five bits [7:3] of the high data byte in two-s complement format and is fixed at –4 (decimal). The remaining 11 bits in two's complement binary format represent the mantissa with the 11th bit fixed at 0 since only positive numbers are considered valid.

Measuring Output Voltage Using the PMBus

The module provides output voltage information using the READ_VOUT command for each output. In this module the output voltage is sensed at the remote sense amplifier output pin so voltage drop to the load is not accounted for. The command will return two bytes of data all representing the mantissa while the exponent is fixed at -9 (decimal).

Reading the Status of the Module using the PMBus

The module supports a number of status information commands implemented in PMBus. However, not all features are supported in these commands. A 1 in the bit position indicates the fault that is flagged.

STATUS_BYTE : Returns one byte of information with a summary of the most critical device faults.

Bit Position	Flag	Default Value
7	Х	0
6	OFF	0
5	VOUT Overvoltage	0
4	IOUT Overcurrent	0
3	VIN Undervoltage	0
2	Temperature	0
1	CML (Comm. Memory Fault)	0
0	None of the above	0

STATUS_WORD : Returns two bytes of information with a summary of the module's fault/warning conditions.

Bit Position	Flag	Default Value
7	Х	0
6	OFF	0
5	VOUT Overvoltage	0
4	IOUT Overcurrent	0
3	VIN Undervoltage	0
2	Temperature	0
1	CML (Comm. Memory Fault)	0
0	None of the above	0

High Byte

Bit Position	Flag	Default Value
7	VOUT fault or warning	0
6	IOUT fault or warning	0
5	Х	0
4	MFR	0
3	POWER_GOOD# (is negated)	0
2	Х	0
1	X	0
0	X	0

STATUS_VOUT : Returns one byte of information relating to the status of the module's output voltage related faults.

Bit Position	Flag	Default Value
7	VOUT OV Fault	0
6	X	0
5	X	0
4	VOUT UV Fault	0
3	X	0
2	X	0
1	X	0
0	X	0

STATUS_IOUT : Returns one byte of information relating to the status of the module's output voltage related faults.

Bit Position	Flag	Default Value
7	IOUT OC Fault	0
6	Х	0
5	IOUT OC Warning	0
4	Х	0
3	X	0
2	Х	0
1	X	0
0	X	0

STATUS_TEMPERATURE : Returns one byte of information relating to the status of the module's temperature related faults.

Bit Position	Flag	Default Value
7	OT Fault	0
6	OT Warning	0
5	Х	0
4	Х	0
3	Х	0
2	Х	0
1	Х	0
0	Х	0

STATUS_CML : Returns one byte of information relating to the status of the module's communication related faults.

Bit Position	Flag	Default Value
7	Invalid/Unsupported Command	0

6	Invalid/Unsupported Command	0
5	Packet Error Check Failed	0
4	Memory Fault Detected	0
3	X	0
2	X	0
1	Other Communication Fault	0
0	X	0

MFR_VIN_MIN : Returns minimum input voltage as two data bytes of information in Linear format (upper five bits are exponent – fixed at -2, and lower 11 bits are mantissa in two's complement format – fixed at 12)

MFR_VOUT_MIN : Returns minimum output voltage as two data bytes of information in Linear format (upper five bits are exponent – fixed at -10, and lower 11 bits are mantissa in two's complement format – fixed at 614)

MFR_SPECIFIC_00 : Returns information related to the type of module and revision number. Bits [7:2] in the Low Byte indicate the module type (010011 corresponds to the UJT035 series of module), while bits [7:3] indicate the revision number of the module.

Low Byte												
Bit Position	Flag	Default Value										
7:2	Module Name	010011										
1:0	Reserved	10										

High Byte

Bit Position	Flag	Default Value
7:3	Module Revision Number	None
2:0	Reserved	000

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Summary of Supported PMBus Commands Please refer to the PMBus 1.1 specification for more details of these commands.

Table 6

Hex Code	Command		Brief Description										
		Turn Module on or o	off. Also	used to	o margii	n the ou	tput vo	ltage			Memory Storage		
		Format			l	Jnsigne	d Binar	у					
		Bit Position	7	6	5	4	3	2	1	0			
		Access	r/w	r	r/w	r/w	r/w	r/w	r	r			
		Function	On	Х			rgin		Х	Х			
01	OPERATION	Default Value	0	0	0	0	0	0	Х	Х			
01		Bit 7:0 Output swit 1 Output s											
		1 Output s Margin: 00XX Margi		y enub	leu								
		0101 Margi		Act on	fault)								
		0110 Marg	in Low (Act on f	fault)								
		1001 Marg											
		1010 Margi							01/05				
		Configures the ON/ and PMBus comma		ictional	ity as a	combin	ation of	analog	ON/OF	F pin			
		Format	nus			Jnsigne	d Rinar	V					
		Bit Position	7	6	5	4	3	2	1	0			
02	ON_OFF_CONFIG	Access	r	r	r	r/w	r/w	r/w	r/w	r	YES		
		Function	Х	Х	Х	pu	cmd	cpr	pol	сра			
		Default Value	0	0	0	1	0	1	1	0			
		Refer to Page 19 for	r details	s on pu,	cmd, cp	or, pol a	nd cpa						
03	CLEAR_FAULTS	Clear any fault bits				et, also i	eleases	s the S№	1BALER	T# signal			
05	CELAIL_I AULIS	if the device has be	en asse	erting it.									
		Used to control writ setting in the modu into non-volatile me Format Bit Position Access	ile whos emory (i 7 r/w	e comr EEPRON 6 r/w	mand co 1) on the 5 r/w	ode mat e modul Jnsigne 4 x	ches th e d Binar 3 x	e value y 2 x	in the c	lata byte			
		Function	bit7	bit6	bit5	Х	Х	Х	Х	Х			
10	WRITE_PROTECT	Default Value	0	0	0	X	X	Х	Х	Х	YES		
10	WMIL_PROTECT	1 – Disables all and ON_OF Bit 6: 0 – Enables al 1 – Disables al OPERATION Bit7: 0 – Enables all 1 – Disables all	 Bit5: 0 – Enables all writes as permitted in bit6 or bit7 1 – Disables all writes except the WRITE_PROTECT, PAGE OPERATION and ON_OFF_CONFIG (bit 6 and bit7 must be 0) Bit 6: 0 – Enables all writes as permitted in bit5 or bit7 1 – Disables all writes except for the WRITE_PROTECT, PAGE and OPERATION commands (bit5 and bit7 must be 0) Bit7: 0 – Enables all writes as permitted in bit5 or bit6 1 – Disables all writes except for the WRITE_PROTECT command (bit5 and bit6 must be 0) 										
15	STORE_USER_ALL	Stores all of the cur new defaults on po		orable re	egister s	ettings	in the E	EPROM	memoi	ry as the			
16	RESTORE_USER_ALL	Restores all of the s (EEPROM). The com switching	mand s	hould n	ot be us	ed whil	e the d	evice is	actively				
		This command help	os the h	ost syst	em/GUI	/CLI det	ermine	key ca	oabilitie	s of the			
		module											
		Format	_		1	Jnsigne		<u> </u>					
		Bit Position	7 r	6 r	5	4 r	3	2 r	1 r	0			
19	CAPABILITY	Access Function	r PEC		r PD	r ALRT	r	r Rese	r erved	r			
		Default Value	1	0	1	1	0	0	0	0			
		PEC – 1 Supported	-	Ŭ		-	. ~	. ~					
		SPD -01 – max of 40 ALRT – 1 – SMBALEF		ported									

Hex Code	Command			Br	ief Desc	ription					Non-Volatile Memory Storage		
Code		The module has MC cannot be changed						-10. Th	ese valu	Jes	Memory Storage		
20		Bit Position Access	7 r	6 r	5 r	4 r	3 r	2 r	1 r	0 r			
20	VOUT_MODE	Function Default Value	0	Mode 0	0	1	6 0	xpone 1	nt 1	1			
		Mode: Value fixed a Exponent: Value fixed	ed at 10)111, E>	kponent				s is -9				
		Sets the value of in	put volt						-				
		Format Bit Position	7	6	inear, tv	4 4	npierrie 3	2	1	0			
		Access	r	r	r	r	r	r	r	r			
		Function			Exponer				Mantiss				
		Default Value Bit Position	1 7	1 6	1 5	1 4	0	0	0	0			
		Access	r	ь r/w	r/w	r/w	r/w	r/w	r/w	r/w			
		Function		1/ 00	17 00		tissa	17 00	1/00	17.00			
35	VIN_ON	Default Value	0	0	0	1	0	0	0	1	YES		
55	VII1_011	Exponent -2 (dec), f Mantissa	ixed			_					123		
		The upper four bits The lower seven and corresponds to a de • 4.25, in s • 9.5V to 1 • 13V to 1											
		Sets the value of in Format	Sets the value of input voltage at which the module turns off Format Linear, two's complement binary										
		Bit Position	7	6	5	4	3	2	1	0			
		Access	r	r	r	r	r	r	r	r			
		Function		1	Exponer	1	-		Mantiss				
		Default Value Bit Position	1 7	1 6	1 5	1 4	0	0	0	0			
		Access	r	r/w	r/w	r/w	r/w	r/w	r/w	r/w			
		Function		.,	17.00		tissa	.,	1,	1,00			
		Default Value	0	0	0	1	0	0	0	0			
36	VIN_OFF	Exponent -2 (dec), f Mantissa The upper four bits The lower seven ard corresponds to a de Allowable values ar 4.00, in s 10.25V t 12V 13.75V t	are fixe e progra efault o e steps of co 11.75 co 15.75	ammab f 4.0V. f 0.25V iV in ind V in ind	upto 9.7 crement	5V. s of 0.5 s of 1V	V				YES		
38	IOUT_CAL_GAIN	Returns the value o output current Format Bit Position Access Function Default Value Bit Position Access	f the go 7 r 1 7 r/w	L 6 r	inear, tw 5 r Exponer 0 5 r/w	vo's cor 4 r t 0 4 r/w	npleme 3 r 1 3 r/w	ent bina 2 r		0 r/w	YES		
		Function Default Value		V· V/	ariable b		tissa n factor	v calibr	ation				
				V: V(u iupie b	iusea ol	Intuctor	y calibr	นแปก				

Hex Code	Command			Br	ief Desc	ription					Non-Volatile Memory Storage
couc		Returns the value c	of the of	fset cor	rection	used to	correct	the me	easured	output	Themory Storage
		current				,					
		Format Bit Position	7	6	inear, tv 5	vo's cor 4	npleme	ent bina 2	ry 1	0	
		Access	r	r	r	r r	r	r/w	r	r	
39	IOUT CAL OFFSET	Function	1		Exponer				Mantiss		YES
55	1001_CAL_011321	Default Value	1	1	1	0	0	V	V	V	TL5
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r/w	r/w	r/w	r/w	r/w	r/w	
		Function					tissa				
		Default Value		V: Vo	ariable b	based o	n factor	y calibr	ation		
		Sets the output ove	ercurren	ıt fault l	evel in A	(cannc	t be ch	anged)			
		Format			inear, tv			1	-		
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r	r	r	r	r	r	
46	IOUT_OC_FAULT_LIMIT	Function	1		Exponer	1	1		Mantiss	1	YES
		Default Value	1	1 6	1 5	1 4	1 3	0	0	0	
		Bit Position Access	/ r	6 r/w	r/w	4 r/w	r/w	2 r/w	1 r/w	r/w	
		Function	1	1/W	17.00		tissa	1/W	1700	17 VV	
		Default Value	0	1	0	1	1	0	1	0	
	Value maybe locked	L			÷		1			-	
		Determines module undervoltage (UV) f	e action	in resp	onse to	an IOU_	_UC_FA		vill or a	VUUI	
		3	uuit								
		Format	7		1	Unsigne			1		
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r/w RS	r/w RS	r/w RS	r	r	r	
47	IOUT_OC_FAULT_RESPONSE	Function	Х	Х	[2]	[1]	[0]	×	Х	Х	YES
		Default Value	0	0	1	1	1	1	0	0	120
		RS[2:0] – Retry Setti 000 Unit do 111 Unit go Any other v	pes not pes thro	ugh no	rmal so	ft start o	continuo	ously			
		Sets the output over			-						
		Format Bit Position	7	6	inear, tv 5	20 S COI	npieme	2	ry 1	0	
		Access	r	r	r	r r	r	r r	r	r	
4A	IOUT OC WARN LIMIT	Function			Exponer		<u> ' </u>		Mantiss		
,		Default Value	1	1	1	1	1	0	0	0	
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r/w	r/w	r/w	r/w	r/w	r/w	r/w	
		Function		_	_		tissa	-	_		
		Default Value	0	1	0	0	1	0	1	0	
		Sets the overtempe	rature	fault lev	vel in °⊂						+
		Format			inear, ti	NO' <u>s co</u> r	mp <u>leme</u>	nt <u>bina</u>	ry		
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r	r	r	r	r	r	
4F		Function			Exponer	nt			Mantiss	a	YES
46	OT_FAULT_LIMIT	Default Value	0	0	0	0	0	0	0	0	YES
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	
		Function		4	4	1	itissa		4		
	Value may be locked	Default Value	0	1	1	1	1	0	1	0	
		T 1	ole 6 ((• • • • •	IN IN						

Table 6 (Continued)

Hex Code	Command				Brief	Descript	tion						Non-Volatile Memory Storage
Couc		Sets the over tempe	oratura	warnin	م امریما ز	n°C Mi	ust he la	wer tha	n OT E		IIMIT		riemory storage
		Format						nt binar					
		Bit Position	7	6	5	4	3	2	1	0	-		
		Access	r	r	r	r	r	r	r	r			
F 1		Function			Exponer	nt		۲	1antisso	1			
51	OT_WARN_LIMIT	Default Value	0	0	0	0	0	0	0	0			YES
		Bit Position	7	6	5	4	3	2	1	0			
		Access	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w			
		Function				1	tissa						
		Default Value	0	1	1	0	1	0	0	1			
		Sets the rise time o	f the o	utput vo	ltage du	iring sta	irtup.						
		Supported Values –							of 0 instr	ucts u	nit to		
		bring its output to p	orograi								_		
		Format			· · · · · ·	1	1	nt binar	, 				
		Bit Position	7	6	5	4	3	2	1	0	_		
61	TON_RISE	Access	r	r	r	r	r	r	r	r/w	4		YES
		Function	1	-	Exponer	1	0		1antissc		-		
		Default Value Bit Position	1 7	1 6	1	0	0	0	0	0	-		
		Access	r/w	r/w	r/w	4 r/w	r/w	∠ r/w	r/w	r/w	-		
		Function	1/ W	17 VV	1700		tissa	1700	1700	1700	-		
		Default Value	0	1	0	0	0	0	1	1	-		
		Returns one byte of		-	-		÷	÷	_	-	ulto		
		Format				Unsigne							
		Bit Position	7	6	5	4	3	2	1	0			
70		Access	r	r	r	r	r	r	r	r	-		
78	STATUS_BYTE				VOUT					None			
		Flag	Х	OFF	VOUT	_	VIN_U V	TEMP	CML	of the			
		Ū			_OV	OC	V			Above	2		
		Default Value	0	0	0	0	0	0	0	0			
		Returns two bytes of	of infor	mation	with a s	ummary	of the	module	s fault/v	warnin	g		
		conditions											
		Format		_	<u> </u>			ned Binc	-	2	1		
		Bit Position		7	6	5	4	3		2	1		
		Access		r	r autria	r	r	r		r	r		
		Flag	V	OUT	OUT/P	Х	MFR	PGOO		×	Х		
79	STATUS_WORD	Default Value		0	OUT 0	0	0	0		о С	0		
	_	Bit Position		7	6	5	4	3		2	-		
					-						1 r	\vdash	
		Access		r	r	r	r	r		r	r	N	
		Flag		х с	FF	VOUT_	IOUT_	O VIN_I	UV TE	мр	CML	No	
				0	9 J	OV	С			- U'	CITL	al	
		Default Value		0	Х	0	0	0	(2	0		
			[:			÷					-		
		Returns one byte of faults	Intorn	nation w	in the s	Status o	i the mo	odule's o	output v	oitage	related	1	
		Format				Unsigne	d Ripan				1		
7A	STATUS_VOUT	Bit Position		7	6 5		4		2 1	0	-		
10	STAT05_0001	Access		r	r ı		r		r r	r			
		Flag		T_OV	XX		JT_UV		X X	X	-		
		Default Value		0	0 0		0		0 C	0			
			a									_	
		Returns one byte of	f inforn	nation w	ith the s	status o	f the mo	odule's o	output c	urrent	related	I	
		faults Format Unsigned Binary									- I		
70		Format Bit Position		7	6	Unsi		nary	/ 7	1	1 0		
7B	STATUS_IOUT	Bit Position	<u> </u>	7 r	6 r		5 r		4 3	2	1 0	-	
		Access Flag		 ΟC Fαι			r OC War	ning	r r X X	r X	r r X X	-	
		Default Value	1001	<u>_OC FUL</u> 0		1001	00 000	mig	0 0		0 0	_	
			1	0		I	5		0	V	0 0		

Hex Code	Command	Brief Description Returns one byte of information with the status of the module's temperature related														Non-Volatile Memory Storage	
			of infor	matic	on wit	th the s	tatus	s of t	he r	nodu	le's	temp	erat	ure r	elated		
		faults Format					Jnsig	ined	Bin	arv							
7D	STATUS_TEMPERATURE	Bit Position		7		6	, norg	5			3	2	1	0			
		Access		r		r		r			r	r	r	r			
		Flag Default Value	OT_	FAUL 0	.Τ	0T_W	ARN	X 0			X 0	X 0	X 0	X 0			
		Returns one byte faults	of infor	matic	on wit	th the s					le's	com	muni	icatio	n relate	ed	
		Format					Uns	igne	d Bi								
75	CTATUS CM	Bit Position	7		6		_	4		3 r	2 r		1		0 r		
7E	STATUS_CML	Access	r		r		M	r emo	ν	1	- 1		r Oth	er	1		
		Flag	Invo Comm			alid PE ta Fa		fault etect	ť	Х	Х		Corr Fau	nm	Х		
		Default Value	0		0			0		0	0		0		0		
			Returns one byte of information with the status of the module specific faults or warning												ng		
		Format		I	r		igneo		-		1						
		Bit Position	7	6	5	4		3	2	1		0					
		Access	r	r	r	r		r	r	r		R		_			
80	STATUS_MFR_SPECIFIC	Flag	OTFI	х	х	IVAD	OR	х	Х	Х	τv	VOPH	H_EN	1			
		Default Value	0	0	0	0		0	0	0		0					
		OTFI – Internal Ter IVADDR – PMBUs (TWOPH_EN – Moc	ddres	s is no	ot val	lid	al Sh	utdo	wn	thres	holo	ł					
		Returns the value	of the (outpu	ıt voli	taae of	the r	modi	ule.	Expo	nen	t is fi	xed	at -9.			
		Format				near, ti											
		Bit Position	7		6	5	4		3		2	1		0	_		
		Access Function	r		r	r	r	antis	r		r	r		٢	_		
8B	READ_VOUT	Default Value	0		0	0	0		0		0	C		0	-		
		Bit Position	7		6	5	4		3		2	1		0			
		Access	r		r	r	r		r		r	r		r			
		Function	0		~	0		antis		_					_		
		Default Value	0		0	0	0		0		0	C		0			
		Returns the value	of the (outpu											_		
		Format	~			near, t\		_		-				0			
		Bit Position Access	7 r		6 r	5 r	4 r	-	3 R		2 r	1 r		0 r	4		
		Function				r xponer			Λ			Mant		1	-1		
8C	READ_IOUT	Default Value	1		1	1	0		0		V	V		V	1		
		Bit Position	7		6	5	4		3		2	1		0			
		Access	r		r	r	r		r		r	r		r	4		
		Function Default Value	V		V	V	V	antis	ssa V		V	V	,	0	-		
		V - Variable	v		v	v	v		v		v			U			

Table 6 (Continued)

Hex Code	Command		Brief Description											
Couc		Returns the value o	f the ex	ternal t	tempera	ture in o	dearee	Celsius				Memory Storage		
		Format			_inear, tv				ry					
		Bit Position	7	6	5	4	3	2	1	0				
		Access	r	r	r	r	R	r	r	r				
		Function			Exponen				Mantiss					
8E	READ_TEMPERATURE_2	Default Value	0	0	0	0	0	V	V	v v				
0L		Bit Position	7	6	5	4	3	2	1	0				
		Access	r	r		r		r		r				
			1		r		r tissa		r					
		Function				-				0				
		Default Value	V	V	V	V	V	V	V	0				
		V - Variable												
		Returns one byte in	dicatio	a tha m	odulo ic	compli	ant to D		noc 11	Iroad o				
		Format	uicutin	y the m			d Binar		pec. 1.1	lieuu u	liy)			
00		Bit Position	7	6	1	<u> </u>		<u> </u>	1	0				
98	PMBUS_REVISION		7	6	5	4	3	2	1	0				
		Access	r	r	r	r	r	r	r	r				
		Default Value	0	0	0	1	0	0	0	1				
		Detune reedule re			_									
		Returns module na	me into	rmation		1	-1.0				l			
		Format	_				d Binar	·						
		Bit Position	/	6	5	4	3	2	1	0				
		Access	r	r	r	r	r	r	r	r				
DO	MFR SPECIFIC 00	Function				Rese	erved	-				YES		
00	MFR_SPECIFIC_00	Default Value	0	0	0	0	0	0	0	0		TLJ		
		Bit Position	7	6	5	4	3	2	1	0				
		Access	r	r	r	r	r	r	r	r				
		Function			Module	Name			Rese	erved				
		Default Value	0	1	0	0	1	1	0	0				
		Applies a fixed offse steps. Permissible v as VREF_TRIMx2 ⁻⁹ . I Format	alues ro	ange be nt fixed	etween -	120mV c)	and +6	0mV. Th	ne offse					
		Bit Position	7	6	5	4	3	2	1	0				
		Access	r/w	r	r	r	r	r	r	r				
D4	VREF_TRIM	Function	.,		· ·	Man	tissa	· ·	. ·			YES		
		Default Value	V	V	V	V	V	V	V	V				
		Bit Position	7	6	5	4	3	2	1	0				
		Access		r	r/w	r/w	r/w	r/w	r/w	r/w				
		Function	r	I	1700		tissa	1700	1700	17 W				
		Default Value	V	V	V	I¶un V	V	V	V	V				
		Default value	V	V	V	V	V	V	V	V				
		Applies a fixed offse Permissible values (STEP_VREF_MARGI voltage includes VF Format	range b N_HIGH	etweer I + VRE M adjus	n 0mV ar F_TRIM)>	nd +60n <2-9. Exp nd rang	nV. The ponent f jes from	offset is fixed at 1 -30%	s calculo -9(dec). to 10%	ated as				
		Bit Position	7	6	5	4	3	2	1	0				
D5	STEP_VREF_MARGIN_HIGH	Access	r	r	r	r	r	r	r	r		YES		
05		Function			<u> </u>		tissa	<u> </u>				TES		
		Default Value	V	V	V	Mun V	V	V	V	V				
		Bit Position	7			4	3		1	0				
				6	5			2						
		Access	r	r	r	r/w	r/w	r/w	r/w	r/w				
		Function					tissa							
1		Default Value	V	V	V	V	V	V	V	V				

Table 6 (Continued)

Hex Code	Command					Bri	ef De	escript	ion					Non-Volatile Memory Storage
		Applies a fix steps. Permi (STEP_VREF_ voltage inclu	issible va _MARGIN	lues rai I_LOW -	nge b + VRE	etwee	n -12 4)x2	20mV (^{.9} .Expo	and Om nent fix	V) The ed at -9	offset is I(dec). N	calculat	ed as	
		Form	at			Lineo	ar, tv	vo's co	mpleme	ent binc	ıry			
		Bit Posi	tion	7	6	5	5	4	3	2	1	0		
D6	STEP VREF MARGIN LOW	Acces	SS	r	r	1	r	r	r	r	r	r		YES
		Functi	on					Mar	ntissa					
		Default \	/alue	V	V	\	/	V	V	V	V	V		
		Bit Posi	tion	7	6	Ę	5	4	3	2	1	0		
		Acces	SS	r	r	r/	W	r/w	r/w	r/w	r/w	r/w		
		Functi	on					Mar	ntissa					
		Default \	/alue	V	V	\	/	V	V	V	V	V		
			ngle command to set PGOOD, VOUT_UNDER_VOLTAGE(UV) and OUT_OVER_VOLTAGE(OV) limits as percentage of nominal											
		Form	nat					l In	isigned	Binary				
		Bit Position		7	-	6	5		4	3	2	1	0	
						-			-	-	_	r/w	-	
		Acce	255	r		r	r		r	r	r	I/W	r/w	
		Function		х		х	Х		х	х	х	PCT_ MSB	PCT_ LSB	
D7		Default	Value	0		Х	Х		Х	Х	Х	0	0	
07	PCT_VOUT_FAULT_PG_LIMIT	PAGE Comm			<u>ا</u>							Ũ	Ű	
		PCT M	PCT LS		-	PG		PG		PGH	PGH			
		SB	B	UV (<i>%</i> 0)	LO		HIG		HIGH	LOW		(%)	
		50				(%		(%		(%)	(%)			
		0	0	-16.	67	-12	- -	-8.3		12.5	8.33	1(5.67	
		-		_					-					
		0	1	-12		-8.3	-	-4.1 -16.		8.33 8.33	4.17		2.5 2.5	
		1	0	-29.		-20.8 -37		-16.	-	8.33 8.33	4.17		2.5	
		_	-		-									
Used to set delay to turn-on or turn-off modules as a ratio of TON_RISE. Values can range from 0 to 7 and are a multiple of TON_RISE TIME														
				a multip	ole of	IUN_F							1	
		Form		7	6				ed Binai		1			
D8	SEQUENCE_TON_TOFF_DELAY	Bit Posi		7	6		5	4	3	2	1	0	-	
		Acces		r/w	r/w N DI		W	r	r/w	r/w OFF DE	r/w	r	-	
		Function Default Value		0	0_0		<u>,</u>	0	0			0	-	
		Default	vulue	U	U)	U	U	0	U	U		

Digital Power Insight (DPI)

GE offers a software tool that set helps users evaluate and simulate the PMBus performance of the UJT035 modules without the need to write software.

The software can be downloaded for free at <u>http://go.ge-energy.com/DigitalPowerInsight.html</u>. A GE USB to I2C adapter and associated cable set are required for proper functioning of the software suite. For first time users, the GE DPI Evaluation Kit can be purchased from leading distributors at a nominal price and can be used across the entire range of GE Digital POL Module.

Thermal Considerations

GE

Power modules operate in a variety of thermal environments; however, sufficient cooling should always be provided to help ensure reliable operation.

Considerations include ambient temperature, airflow, module power dissipation, and the need for increased reliability. A reduction in the operating temperature of the module will result in an increase in reliability. The thermal data presented here is based on physical measurements taken in a wind tunnel. The test set-up is shown in Figure 42. The preferred airflow direction for the module is in Figure 43.

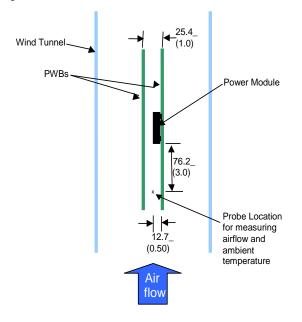


Figure 42. Thermal Test Setup.

The thermal reference point, T_{ref} used in the specifications is shown in Figure 43. For reliable operation, the temperature at this points should not exceed 115°C. The output power of the module should not exceed the rated power of the module (Vo,set x Io,max).

Please refer to the Application Note "Thermal Characterization Process For Open-Frame Board-Mounted Power Modules" for a detailed discussion of thermal aspects including maximum device temperatures.

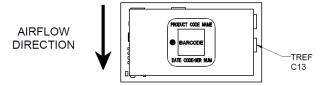


Figure 43. Preferred airflow direction and location of hotspot of the module (Tref).

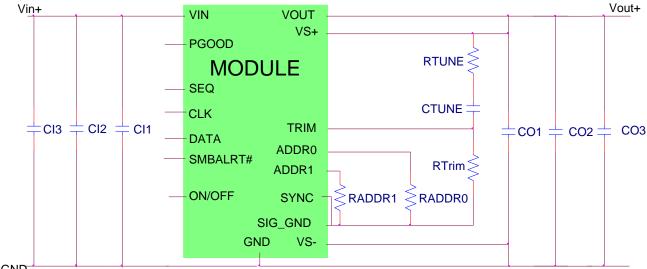
35A Digital MicroDLynxII[™]: Non-Isolated DC-DC Power Modules

4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

Example Application Circuit

<u>Requirements:</u> Vin: 12V

Vout:	1.8V
lout:	26A max., worst case load transient is from 17.5A to 26A
∆Vout:	1.5% of Vout (27mV) for worst case load transient
Vin, ripple	1.5% of Vin (180mV, p-p)



GND

CI1

_	Decoupling caps - 1x0.047µF/16V 0402 or 0306ceramic capacitor (e.g. Murata LLL185R71C473MA01) +
	1x0.1uF/16V 0402 ceramic cpacitor

- CI2 6x22µF/16V ceramic capacitor (e.g. Murata GRM32ER61C226KE20)
- CI3 47µF/16V bulk electrolytic
- CO1 Decoupling cap 1x0.047µF/16V ceramic capacitor (e.g. Murata LLL185R71C473MA01) + 1x0.1uF/16V 0402 ceramic cpacitor
- CO2 8 x 47uF/6.3V 1210 ceramic capacitor
- CO3 4 x 330uF/6V POSCAP
- CTune 3300pF ceramic capacitor (can be 1206, 0805 or 0603 size)
- RTune 300Ω SMT resistor (can be 1206, 0805 or 0603 size)
- RTrim $10k\Omega$ SMT resistor (can be 1206, 0805 or 0603 size, recommended tolerance of 0.1%)

<u>Note:</u> The DATA, CLK and SMBALRT pins do not have any pull-up resistors inside the module. Typically, the SMBus master controller will have the pull-up resistors as well as provide the driving source for these signals.

35A Digital MicroDLynxIITM: Non-Isolated DC-DC Power Modules

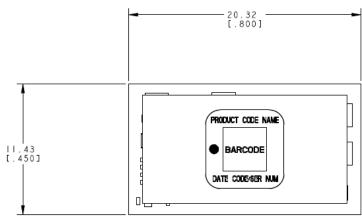
4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

Mechanical Outline

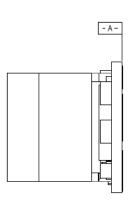
Dimensions are in millimeters and (inches).

Tolerances: x.x mm \pm 0.5 mm (x.xx in. \pm 0.02 in.) [unless otherwise indicated]

x.xx mm \pm 0.25 mm (x.xxx in \pm 0.010 in.)



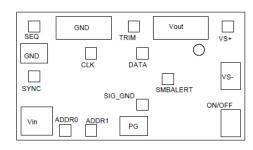
TOP VIEW



SIDE VIEW

PIN

1



BOTTOM VIEW



FUNCTION

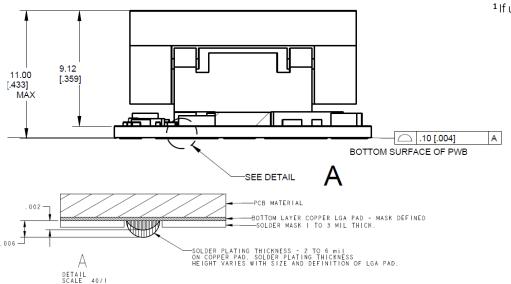
ON/OFF

PIN

10

FUNCTION

SYNC²



35A Digital MicroDLynxII[™]: Non-Isolated DC-DC Power Modules

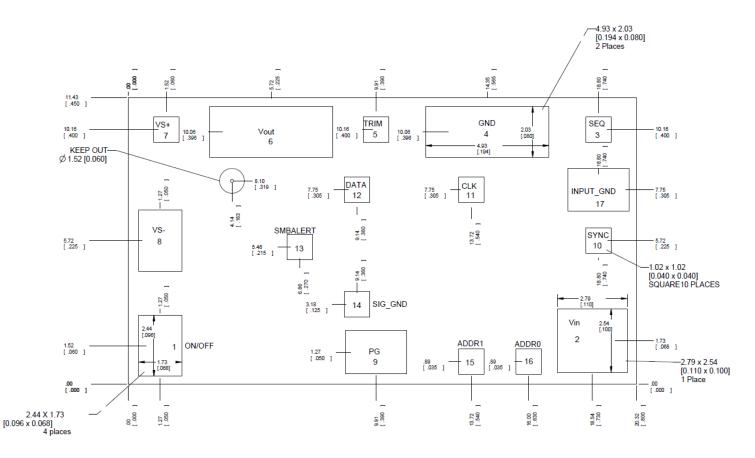
4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

Recommended Pad Layout

Dimensions are in millimeters and (inches).

Tolerances: x.x mm \pm 0.5 mm (x.xx in. \pm 0.02 in.) [unless otherwise indicated]

x.xx mm \pm 0.25 mm (x.xxx in \pm 0.010 in.)



PIN	FUNCTION	PIN	FUNCTION		
1	ON/OFF	10	SYNC ²		
2	VIN	11	CLK		
3	SEQ	12	DATA		
4	GND	13	SMBALERT#		
5	TRIM	14	SIG_GND		
6	VOUT	15	ADDR1		
7	7 VS+		7 VS+ 16		ADDR0
8	8 VS-		INPUT_GND		
9	PG				

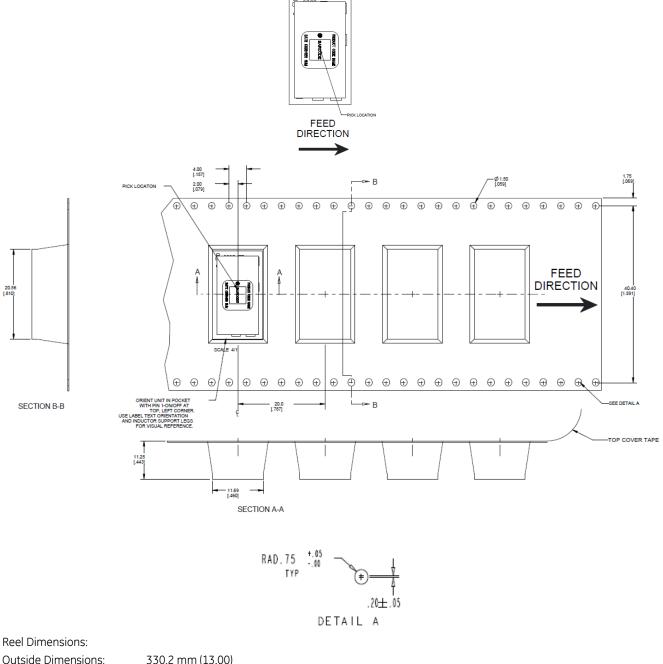
² If unused, connect to SIG_GND.

GE

Packaging Details

The 12V Digital MicroDLynxII[™] 35A modules are supplied in tape & reel as standard. Modules are shipped in quantities of 200 modules per reel.

All Dimensions are in millimeters and (in inches).



Outside Dimensions: Inside Dimensions: Tape Width:

330.2 mm (13.00) 177.8 mm (7.00") 44.00 mm (1.732")

Surface Mount Information

Pick and Place

GF

The 35A Digital MicroDLynxII[™] modules use an open frame construction and are designed for a fully automated assembly process. The modules are fitted with a label designed to provide a large surface area for pick and place operations. The label meets all the requirements for surface mount processing, as well as safety standards, and is able to withstand reflow temperatures of up to 300°C. The label also carries product information such as product code, serial number and the location of manufacture.

Nozzle Recommendations

The module weight has been kept to a minimum by using open frame construction. Variables such as nozzle size, tip style, vacuum pressure and placement speed should be considered to optimize this process. The minimum recommended inside nozzle diameter for reliable operation is 3mm. The maximum nozzle outer diameter, which will safely fit within the allowable component spacing, is 7 mm.

Bottom Side / First Side Assembly

This module is not recommended for assembly on the bottom side of a customer board. If such an assembly is attempted, components may fall off the module during the second reflow process.

Lead Free Soldering

The modules are lead-free (Pb-free) and RoHS compliant and fully compatible in a Pb-free soldering process. Failure to observe the instructions below may result in the failure of or cause damage to the modules and can adversely affect long-term reliability.

Pb-free Reflow Profile

Power Systems will comply with J-STD-020 Rev. C (Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices) for both Pb-free solder profiles and MSL classification procedures. This standard provides a recommended forced-air-convection reflow profile based on the volume and thickness of the package (table 4-2). The suggested Pb-free solder paste is Sn/Ag/Cu (SAC). For questions regarding Land grid array(LGA) soldering, solder volume; please contact GE for special manufacturing process instructions. The recommended linear reflow profile using Sn/Ag/Cu solder is shown in Fig. 44. Soldering outside of the recommended profile requires testing to verify results and performance.

MSL Rating

The 35A Digital MicroDLynxII^m modules have a MSL rating of 2A.

Storage and Handling

The recommended storage environment and handling procedures for moisture-sensitive surface mount packages is detailed in J-STD-033 Rev. A (Handling, Packing, Shipping and Use of Moisture/Reflow Sensitive Surface Mount Devices). Moisture barrier bags (MBB) with desiccant are required for MSL ratings of 2 or greater. These sealed packages should not be broken until time of use. Once the original package is broken, the floor life of the product at conditions of \leq 30°C and 60% relative humidity varies according to the MSL rating (see J-STD-033A). The shelf life for dry packed SMT packages will be a minimum of 12 months from the bag seal date, when stored at the following conditions: $< 40^{\circ}$ C, < 90% relative humidity.

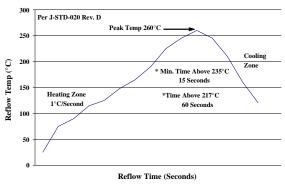


Figure 44. Recommended linear reflow profile using Sn/Ag/Cu solder.

Post Solder Cleaning and Drying Considerations

Post solder cleaning is usually the final circuit-board assembly process prior to electrical board testing. The result of inadequate cleaning and drying can affect both the reliability of a power module and the testability of the finished circuit-board assembly. For guidance on appropriate soldering, cleaning and drying procedures, refer to *Board Mounted Power Modules: Soldering and Cleaning* Application Note (AN04-001).

GF

35A Digital MicroDLynxII[™]: Non-Isolated DC-DC Power Modules 4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

Ordering Information

Please contact your GE Sales Representative for pricing, availability and optional features.

Table 9. Device Codes

	Device Code	e Code Input Output Voltage Range Voltage		Output Current	On/Off Logic	Sequencing	Comcodes
F	UJT035A0X3-SRZ	4.5 – 14.4Vdc	0.51 – 3.63Vdc	35A	Negative	Yes	150047126
ſ	UJT035A0X43-SRZ	4.5 – 14.4Vdc	0.51 – 3.63Vdc	35A	Positive	Yes	150047127

-Z refers to RoHS compliant parts

Table 10. Coding Scheme

Package Identifier	Family	Sequencing Option	Output current	Output voltage	On/Off logic	Remote Sense	Options		ROHS Compliance
U	J	Т	035A0	X		3	-SR		Z
P=Pico U=Micro M=Mega G=Giga	J=DLynx II Digital K = DLynxII Analog.	T=with EZ Sequence X=without sequencing	35A	X = programm able output	4 = positive No entry = negative	3 = Remote Sense	S = Surface Mount R = Tape & Reel	No entry = Standard	Z = ROHS6

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